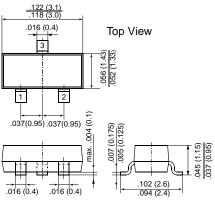
MMBD914

SMALL SIGNAL SWITCHING DIODE

SOT-23 .016 (0.4) Top View 1 2 .037(0.95) .037(0.95) 9 6 9 .007 (0.175)



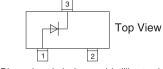
FEATURES

- ♦ Silicon Epitaxial Planar Diode
- ♦ Fast switching diode in case SOT-23, especially suited for automatic insertion.



MECHANICAL DATA

Case: SOT-23 Plastic Package Weight: approx. 0.008 g Marking Code: 5D



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	Symbol	Value	Unit
Peak Reverse Voltage	V_{RM}	100	V
Maximum Average Recticified Current	Io	200	mA
Maximum Power Dissipation at T _{amb} = 25°C	P _{tot}	225	mW
Maximum Junction Temperature	Tj	150	°C
Storage Temperature Range	T _S	-55 to +150	°C
Maximum Forward Voltage Drop at 1 _F = 10 mA	V _F	1.0	V
Maximum Reverse Current at VR = 20V VR = 75 V	I _R	25 5.0	nA μA
Max. Reverse Recovery Time at $I_F = I_R = 10 \text{mA}$, $V_R = 6 \text{V}$ $R_L = 100 \Omega$ to $I_{rr} = 1 \text{ mA}$	t _{rr}	4.0	ns
Maximum Capacitance at V _R =0, f=1.0 MHz	Ctot	4.0	pF

